
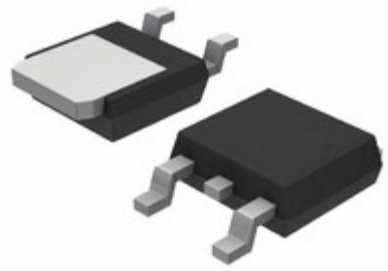
	<h2 style="color: red;">NTD3055L170G</h2>
	<p>Hersteller-Teilenummer: NTD3055L170G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 9A DPAK</p> <hr/> <p>Datenblätter:  NTD3055L170G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 5069 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD3055L170G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 9A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5069 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.5W (Ta), 28.5W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9A (Ta)
Rds On (Max) @ Id, Vgs	170 mOhm @ 4.5A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	10nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	275pF @ 25V
Verpackung	Tube


















































NTD3055L170G ist neu im Original, Suche NTD3055L170G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD3055L170G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD3055L170G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD3055L170-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A IPAK</p>	 <p>NTD3055L170T4 ON NTD3055L170T4 ON</p>	 <p>NTD3055L170T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A DPAK</p>	 <p>NTD3055L104T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A DPAK</p>
 <p>NTD3055VLT4G ON NTD3055VLT4G ON</p>	 <p>NTD3055LT4G O NTD3055LT4G O</p>	 <p>NTD3055L170 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A DPAK</p>	 <p>NTD3055L170-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A IPAK</p>

heiße Teile

Mehr

 NTD2955T4	 NTD2955T4G	 NTD2955V	 NTD2955VT4G	 NTD3055-094
 NTD3055-094-1G	 NTD3055-094G	 NTD3055-094T4	 NTD3055-094T4G	 NTD3055-150
 NTD3055-150-1G	 NTD3055-150G	 NTD3055-150T4	 NTD3055-150T4G	 NTD3055-170T4G
 NTD3055L104T4G	 NTD3055L	 NTD3055L04T4G	 NTD3055L104	 NTD3055L104-1G
 NTD3055L104G	 NTD3055L104T4G	 NTD3055L170	 NTD3055L170-001	 NTD3055L170-1G
 NTD3055L170T4	 NTD3055L170T4G	 NTD3055LT4G	 NTD3055VLT4G	 NTD30N02G
 NTD30N02T4	 NTD30N02T4G	 NTD30N06RT4	 NTD30N06T4G	 NTD32N06-001
 NTD32N06-1G	 NTD32N06G	 NTD32N06L	 NTD32N06L-001	 NTD32N06L-1G
 NTD32N06LG	 NTD32N06LT4G	 NTD32N06T4G	 NTD3808NT4G	 NTD3813NT4G
 NTD3817NT4G	 NTD40N03R	 NTD40N03R-1	 NTD40N03R-1G	 NTD40N03RG

Contact us: Info@Y-IC.com

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